Supplementary Information (SI) for Journal of Materials Chemistry A. This journal is © The Royal Society of Chemistry 2025

## Cu-Decorated Sc<sub>2</sub>CFN Monolayer for Efficient CO<sub>2</sub> Capture and Activation

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## Supplementary data

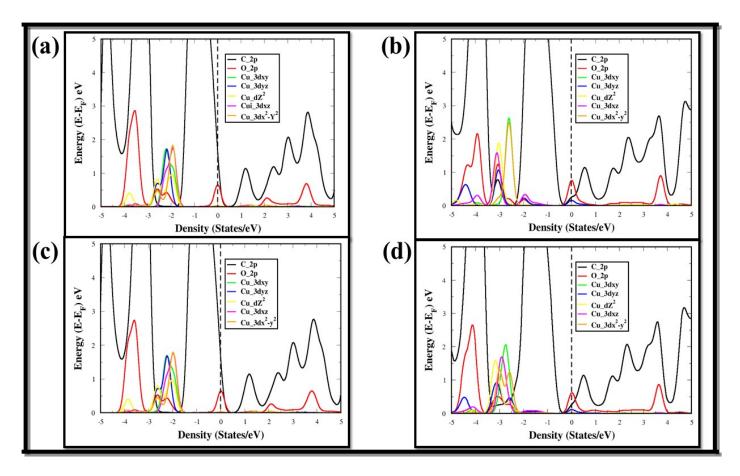


Figure S1. Shows Projected density of states (PDOS) showing the interaction between Cu 3d orbitals and CO<sub>2</sub> 2p orbitals at different adsorption sites of Cu-decorated Sc<sub>2</sub>CFN: (a) N, (b) F, (c) Sc+F, and (d) Sc+N. The strongest hybridization occurs at the N-site,

The orbital-resolved PDOS analysis (Figure S1) provides insight into the interaction mechanism between the Cu atom and CO<sub>2</sub> molecules adsorbed on different sites of the Sc<sub>2</sub>CFN surface. In all cases, there is noticeable overlap between the Cu 3d orbitals and the CO<sub>2</sub> O-2p states in the energy range from –5 eV to 0 eV, confirming hybridization and charge transfer that contribute to CO<sub>2</sub> activation.

- ➤ At the N-terminated site (Figure S1a), the Cu 3d<sub>xz</sub> and 3d<sub>yz</sub> orbitals exhibit the strongest overlap with the O-2p orbitals, consistent with the enhanced bending of CO<sub>2</sub> and higher adsorption energy.
- At the **F-terminated site** (Figure S1b), the overlap is weaker and mainly involves the Cu 3d<sub>xv</sub> orbital, leading to less pronounced CO<sub>2</sub> activation.
- For the Sc+F site (Figure S1c), hybridization occurs through the  $3d_{xz}/3d_{yz}$  and  $3d_{x^2-y^2}$  orbitals, resulting in moderate CO<sub>2</sub> activation compared to the N-site.
- ➤ At the Sc+N site (Figure S1d), partial contributions from 3dz² and 3d<sub>xz</sub> orbitals are observed, but the overlap is weaker compared to the N-site, consistent with lower activation strength.

Overall, these results confirm that the N-terminated Cu-decorated Sc<sub>2</sub>CFN provides the most favourable orbital interactions for CO<sub>2</sub> activation, with the Cu  $3d_{xz}/3d_{yz}$  orbitals playing the dominant role in hybridization with the O-2p orbitals of CO<sub>2</sub>.

For the N-activated site, the adsorption is characterized by significant overlap between the C-2p/O-2p states of CO<sub>2</sub> and the Cu- $d_{xz}/d_{yz}$  orbitals (-4.0 to -2.0 eV), with weaker contributions from Cu-dz<sup>2</sup>. This indicates that CO<sub>2</sub> interacts preferentially through lateral d-orbitals when coordinated to N, contrasting with the F-activated site where the Cu-dz<sup>2</sup> orbital dominates.

The interaction between  $CO_2$  and the F-activated Cu center is mediated primarily by the Cud\_z² orbital, evidenced by its pronounced energy-aligned overlap with C-2p/O-2p features ( $\approx$  3.5 to -1.0 eV) and residual mixing around  $E_F$ , while dxz/dyz contribute weakly and dxy/dx²-y² show minimal participation At the Sc+F co-doped site, the PDOS reveals that the Cu-dxz and dyz orbitals are primarily responsible for hybridization with the C-2p/O-2p states in the -4.5 to -2.5 eV region. In addition, weaker contributions from Cu-dz² and dx²-y² are evident, suggesting a more complex multi-orbital interaction compared with the isolated F or N active sites For the Sc+N co-doped site, the interaction of  $CO_2$  with the Cu center involves significant contributions from the in-plane Cu-dxy, dxz, and dyz orbitals, which overlap strongly with C-2p/O-2p states around -4.0 to -2.0 eV. Additionally, moderate involvement of Cu-dz² and dx²-

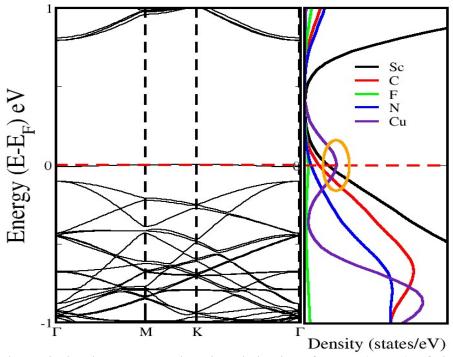


Figure S2. Electronic band structure and projected density of states (PDOS) of the Cu-doped Sc<sub>2</sub>CFN monolayer. The Fermi level is set to zero (red dashed line). The system retains an indirect band gap nature, while the gap value is reduced due to Cu-induced states. Strong hybridization between Cu, Sc, and N orbitals near the Fermi level (highlighted region) indicates enhanced electronic interactions that narrow the band gap.

y<sup>2</sup> orbitals is detected, pointing to a more delocalized and multi-orbital hybridization mechanism than in either the F- or N-only sites

Here, in Figure S2 Shows the indirect nature of the band gap remains in the Cu-doped F-active site of Sc<sub>2</sub>CFN monolayer, as the VBM and CBM still occur at different k-points. However, the band gap value is reduced (narrowed) compared to pristine Sc<sub>2</sub>CFN, due to the Cu-induced states near the Fermi level. In fact, if the Cu contribution is strong enough, (shown in orange circle) the system can even approach semi metallic behavior depending on the doping concentration.

Table S1. Adsorption energies (Eads, in eV) of CO<sub>2</sub> on Cu-decorated Sc<sub>2</sub>CFN monolayer for horizontal (HCO<sub>2</sub>) and vertical (VCO<sub>2</sub>) configurations at different adsorption sites.

Eads (HCO <sub>2</sub> ) [eV]	Eads (VCO <sub>2</sub> ) [eV]
-0.60	-0.29
-0.92	-0.43
-0.83	-0.58
-0.59	-0.71
	-0.60 -0.92 -0.83

Table S2. Adsorption energies (E\_ads, in eV) of Cu on Sc<sub>2</sub>CFN monolayer at different adsorption sites calculated with vdW correction

Eads (eV)
-0.67
-1.70
-1.27
-1.82

Table S3. Adsorption energies (Eads, in eV) of CO<sub>2</sub> on Cu-decorated Sc<sub>2</sub>CFN monolayer at different adsorption sites, calculated with vdW correction

<b>Adsorption Site</b>	Eads (eV)
F	-2.49
N	-1.95
Sc+F	-1.89
Sc+N	-1.53

Table S4. Comparison of CO<sub>2</sub> adsorption energies (Eads, in eV) on different MXene systems from literature and this work.

MXene system	Eads (eV)	Reference	Ref.No
Ti <sub>2</sub> CO <sub>2</sub>	-0.45 to -1.10	CO2 abatement by two- dimensional MXene carbides	1
V <sub>2</sub> CO <sub>2</sub>	-0.60 to -1.30	CO2 abatement by two- dimensional MXene carbides	1
Mo <sub>2</sub> CO <sub>2</sub>	-0.50 to -1.20	Carbon dioxide adsorption of two-dimensional Mo2C MXene	2
W <sub>2</sub> C, Cr <sub>2</sub> C, Nb <sub>2</sub> C (various)	-1.22 to -3.65	Carbon dioxide adsorption of two-dimensional Mo2C MXene	2
Ti <sub>2</sub> C–Cu	-1.40 to -2.00	Ti2CMXene/activated carbon Nanocomposite for efficient CO2 capture: Insights into thermodynamics properties	3
V <sub>2</sub> C–Cu	-1.60 to -2.20	Ti2C-MXene/activated carbon nanocomposite for efficient CO2 capture: Insights into thermodynamics properties	3
Sc <sub>2</sub> CFN–Cu (this work)	-1.53 to -2.49	This work	

Table S4 compares our adsorption results with those of similar MXene systems reported in the literature. For pristine MXenes such as  $Ti_2CO_2$  and  $V_2CO_2$ ,  $CO_2$  adsorption energies typically range from -0.45 to -1.30 eV, indicative of moderate chemisorption. Metal decoration, such as Cu on  $Ti_2C$  or  $V_2C$ , strengthens adsorption into the range of -1.40 to -2.20 eV. In our case, Cu-decorated Sc<sub>2</sub>CFN exhibits adsorption energies between -1.53 and -2.49 eV (vdW corrected), which are in excellent agreement with reported Cu-decorated MXenes. Importantly, while Sc<sub>2</sub>CFN–Cu demonstrates strong activation, the adsorption energies remain below the extreme values ( $\approx -3.65$  eV) observed for some pristine MXenes, suggesting that  $CO_2$  desorption remains feasible under photocatalytic conditions.

## References

- 1 Á. Morales-García, A. Fernández-Fernández, F. Viñes and F. Illas, .
- S. Jin, Y. Guo, J. Wang, L. Wang, Q. Hu and A. Zhou, *Diam Relat Mater*, 2022, **128**, 109277.
- 3 M. Aliyu, B. O. Yusuf, A. H. S. Abdullahi, A. I. Bakare, M. Umar, A. S. Hakeem and S. A. Ganiyu, *Sep Purif Technol*, 2024, **340**, 126737.